

In the Claims:

This listing of claims will replace all prior versions, and listings, of claims in the application:

- 1 1. (Currently Amended) A reflective liquid crystal display device comprising:
2 a semiconductor substrate;
3 at least one pair of pixel switching transistor and a capacitor
4 formed on the semiconductor substrate and electrically isolated from
5 each other;
6 a first interlayer insulating layer formed on the pixel switching
7 transistor and the capacitor;
8 a wiring layer formed on the first interlayer insulating layer;
9 a second interlayer insulating layer formed over the wiring layer;
10 a light shielding layer formed on the second interlayer insulating
11 layer;
12 a third interlayer insulating layer formed over the light shielding
13 layer;
14 at least one pixel electrode formed on the third interlayer insulating
15 layer;
16 a common electrode formed over the pixel electrode;
17 a liquid crystal layer provided between the pixel electrode and the
18 common electrode;
19 a light-transmissive substrate formed on the common electrode;
20 and
21 at least one anti-reflection layer formed on either the wiring layer
22 or the light shielding layer, the anti-reflection layer being a double layer of
23 a metallic film of TiN or Ti and a silicon oxynitride film that exhibits a
24 refraction index different from a refraction index of the third interlayer
25 insulating layer.
- 1 2. (Original) The reflective liquid crystal display device according to claim 1
2 further comprising a first anti-reflection layer formed on the wiring layer and a

3 second anti-reflection layer formed on the light shielding layer, each anti-
4 reflection layer being a double layer of a metallic film and a silicon oxynitride film
5 that exhibits a refraction index different from a refraction index of the third
6 interlayer insulating layer.

1 3-5 Cancelled

1 6. (Original) The reflective liquid crystal display device according to claim 1,
2 wherein the refraction index of the silicon oxynitride film is in the range from 1. 7
3 to 1. 9.

1 7. (Original) The reflective liquid crystal display device according to claim 1,
2 wherein a thickness of the silicon oxynitride film is in the range from 400 to 600
3 Å.

1 8. (New) The reflective liquid crystal display device according to claim 1,
2 where a thickness of the metallic film is smaller than 300 nm.

1 9. (New) The reflective liquid crystal display device according to claim 1,
2 wherein a thickness of the metallic film is about 800 Å.